High Voltage Low Power Consumption LDO

MD7680 Series

CMOS Voltage Regulator With ON/OFF Switch

150mA



MD7680 is a high voltage (up to 60V) ultra-low quiescent current low dropout voltage regulator (LDO) manufactured in CMOS processes. It can deliver up to 150mA of current while consuming only 2.3uA of quiescent current. It consists of a reference voltage generator, an error amplifier, a current foldback circuit, and a phase compensation circuit plus a driver transistor. The MD7680 is designed specifically for applications where very-low I_Q is a critical parameter. This device

maintains low quiescent current consumption even in dropout mode to further increase the battery life. When in shutdown or disabled mode, the device consumes less than 100-nA I_Q even with input voltage of 60V that helps increase the shelf life of the battery.

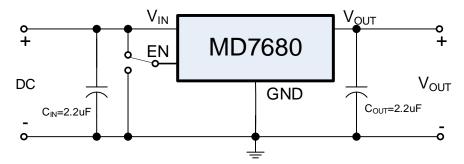
Features

- Ultra-low Quiescent Current: 2.3uA
- Maximum Input Voltage: 60V
- Output Voltage Highly Accurate: ±2%
- Maximum Output Current: 150mA
- Dropout Voltage: 8mV@I_{OUT}=1mA
- Temperature Stability: ±40ppm/℃
- ON/OFF Logic = Enable High
- Protections Circuits: Current Limiter, Foldback, Thermal shutdown
- Output Capacitor: Low ESR Ceramic Capacitor Compatible

Applications

- Smart wearer
- Long-life battery-powered devices
- Portable mobile devices, such as mobile phones, cameras, and so on
- Wireless communication equipment

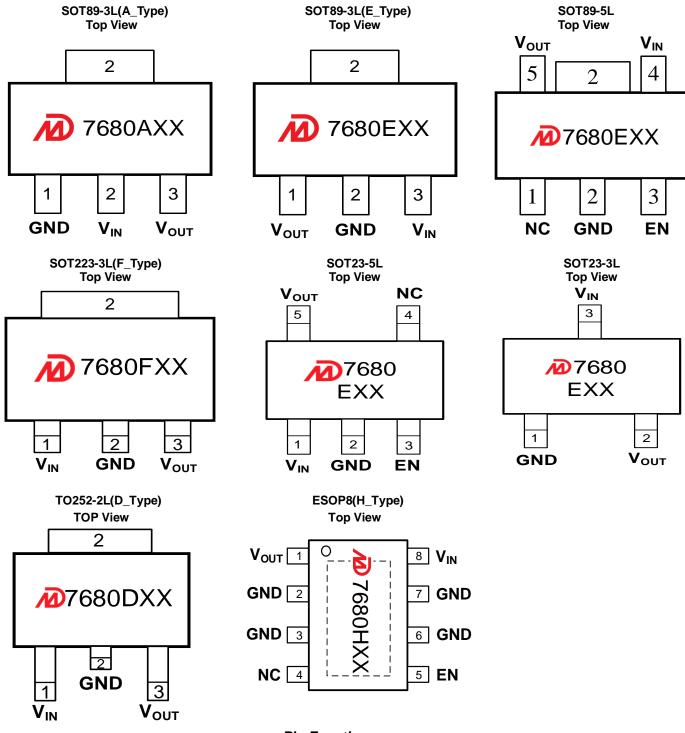
■ Typical Applications



Notes on Use

Input Capacitor (C_{IN}): 2.2 μ F above Output Capacitor (C_{OUT}): 2.2 μ F above

■ Pin Configuration and Functions



Pin Functions

NAME	DESCRIPTION
V _{IN}	Power Input Pin.
EN	Enable pin. Drive this pin high to enable the device. Drive this pin low to put the device into low current shutdown.
V _{OUT}	Regulated output voltage pin
GND	Ground

Notes: Customer can request to customize other packages with or without EN pin.

■ Product Selections

Product Name	V _{OUT} (V)	Package	Ordering Name	Marking	Package Information
MD7680A33	3.3	SOT89-3L	MD7680A33PA1	₹ 7680A33	
MD7680A36	3.6	SOT89-3L	MD7680A36PA1	₹ 7680A36	
MD7680A50	5.0	SOT89-3L	MD7680A50PA1	₹ 7680A50	Tape and Reel, 1000pcs
MD7680AC0	12.0	SOT89-3L	MD7680AC0PA1	₹ 7680AC0	Тооброб
MD7680AF0	15.0	SOT89-3L	MD7680AF0PA1	₹ 7680AF0	
MD7680E33	3.3	SOT89-3L	MD7680E33PA1	₹ 7680E33	
MD7680E50	5.0	SOT89-3L	MD7680E50PA1	₹ 7680E50	Tape and Reel, 1000pcs
MD7680EC0	12.0	SOT89-3L	MD7680EC0PA1	₹ 7680EC0	1000000
MD7680E33	3.3	SOT89-5L	MD7680E33PC1	₹ 7680E33	
MD7680E50	5.0	SOT89-5L	MD7680E50PC1	₱7680E50	Tape and Reel, 1000pcs
MD7680EC0	12.0	SOT89-5L	MD7680EC0PC1	₹ 7680EC0	1000000
MD7680F33	3.3	SOT223-3L	MD7680F33YA2	₱7680F33	
MD7680F50	5.0	SOT223-3L	MD7680F50YA2	№ 7680F50	Tape and Reel, 2500pc
MD7680FC0	12.0	SOT223-3L	MD7680FC0YA2	₹ 7680FC0	200000
MD7680E33	3.3	SOT23-5L	MD7680E33QC3	₹ 7680E33	
MD7680E50	5.0	SOT23-5L	MD7680E50QC3	₹ 7680E50	Tape and Reel, 3000pc
MD7680EC0	12.0	SOT23-5L	MD7680EC0QC3	₹ 7680EC0	000000
MD7680E33	3.3	SOT23-3L	MD7680E33QA3	₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱	
MD7680E50	5.0	SOT23-3L	MD7680E50QA3	₹ 7680E50	Tape and Reel, 3000pc
MD7680EC0	12.0	SOT23-3L	MD7680EC0QA3	₹ 7680EC0	000000
MD7680D33	3.3	TO252-2L	MD7680D33UA2	₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱₱	
MD7680D50	5.0	TO252-2L	MD7680D50UA2	₹ 7680D50	Tape and Reel, 2500pcs
MD7680DC0	12.0	TO252-2L	MD7680DC0UA2	₩7680DC0	2000μοσ
MD7680H33	3.3	ESOP8	MD7680H33SF4	₱7680H33	
MD7680H50	5.0	ESOP8	MD7680H50SF4	₹ 7680H50	Tape and Reel, 4000pcs
MD7680HC0	12.0	ESOP8	MD7680HC0SF4	₩7680HC0	400000

Notes:

^{1*} Customer can request to customize the output voltage ranged from 1.2V to 15V if desired voltage is not found in the selection s.

^{2*} Customer can request customization of package choice.

^{3*} Please pay attention to the MARKING of the product package type.

■ Absolute Maximum Ratings (Unless otherwise indicated: T_a=25°C)

PARAMETER	SYMBOL	RATI	UNITS		
Input Voltage	V_{IN}	-0.3 ~ 65		V	
Output Voltage	V_{OUT}	Vss-0.3 ~ VIN+0.3V		V	
		ESOP8	1800		
		TO252-2L	1800		
		SOT223-3L	1500		
Power Dissipation	P _D	SOT89-5L	1000	mW	
		SOT89-3L	1000		
		SOT23-5L	250		
		SOT23-3L	250		
	R _{ÐJA}	ESOP8	80		
			TO252-2L	55	
		SOT223-3L	66		
Thermal Resistance		SOT89-5L	100	°C/W	
		SOT89-3L	100		
		SOT23-5L	250		
		SOT23-3L	250		
Operating Ambient Temperature	T _{opr}	-40 ~ +85		°C	
Storage Temperature	T_{stg}	-40 ~ +125			
ESD Protection	ESD HBM	7000		V	
Humidity sensitive level	MSL		3		

Note: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

■ Electrical Characteristics

MD7680 Series (Unless otherwise indicated: T_a=25℃)

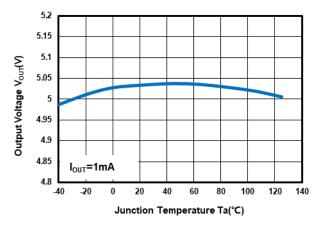
			/				
PARAMETER	SYMBOL	CONDITIONS		MIN.	TYP.	MAX.	UNIT
Output Voltage*1	V _{OUT(S)}	V _{IN} = V _{OUT(S)} +2V, I _{OUT} =1mA		V _{OUT(S)} × 0.98	V _{OUT(S)}	V _{OUT(S)} × 1.02	V
Dropout Voltage*2	V	$V_{EN}=V_{IN}, V_{OUT(S)}=5.0V$ $I_{OUT}=1mA$			8	16	- mV
Dropout Voltage	V_{DROP}	$V_{EN}=V_{IN}, V_{OUT(S)}=5.0V$ $I_{OUT}=150mA$			1300	1800	
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \bullet V_{OUT(s)}}$	V _{OUT(S)} +2V≤V _{IN} ≤60V I _{OUT} =1mA			0.01	0.02	%/V
Land Day 1989	/	$V_{IN} = V_{OUT(S)} + 2V$	V _{OUT(S)} ≤5.3V		20	40	mV
Load Regulation	ΔV_{OUT2}	1mA≤l _{OUT} ≤150mA	V _{OUT(S)} >5.3V		50	80	
Temperature Stability	$\frac{\Delta V_{OUT}}{\Delta T_{a} \bullet V_{OUT(s)}}$	$V_{IN} = V_{OUT(S)} + 2V$, $I_{OUT} = 10$ mA $-40^{\circ}\text{C} \le T_a \le 125^{\circ}\text{C}$			±40		ppm/℃
			V _{OUT(S)} <3.0V	0.8	1.2	2.5	
0.17.0		no load (Vουτ(s)+2V≤Vικ≤55V)	3.0≤V _{OUT(S)} ≤5.3V	1	2.3	3	
GND Current $(V_{EN}=V_{IN})$	I_{GND}		V _{OUT(S)} >5.3V	1.5	3	4.5	
(VEN-VIN)		no load (55V <v<sub>IN≤60V)</v<sub>			10	30	uA
		I _{OUT} =100mA			1100		
Shutdown Current (EN=0)	I _{SHUT}	V _{IN} =60V, V _{EN} =0			0.1	1	
Input Voltage	V _{IN}			2.2		60	V
Maximum Output Current	I _{OUTMAX}			150			
Current Limit*3	I _{LIM}	$V_{EN}=V_{IN}=V_{OUT(S)}+2V,$ $V_{OUT}=0.95 \times V_{OUT(S)}$			240		mA
Short Circuit Current*4	I _{SHORT}	$V_{IN}=V_{EN}=V_{OUT(S)}+2.0V$ $V_{OUT}=0V$			10		
		f=10Hz, I _O	_{UT} =10mA		76		
Power Supply Rejection Ratio	PSRR	f=100Hz, I _{OUT} =10mA			80		dB
		f=1kHz, I _{OUT} =10mA			63		
EN 'H' Level Voltage	V_{ENH}			1.5		60	V
EN 'L' Level Voltage	V_{ENL}			0		0.6	v
EN 'H' Level Current	I _{ENH}	V _{IN} =60V, V _{EN} =V _{IN}		-0.1		0.1	uA
EN 'L' Level Voltage	I _{ENL}	V _{IN} =60V, V _{EN} =0		-0.1		0.1	uA
Over Temperature Protection	ОТР	I _{OUT} =1mA			165		$^{\circ}$

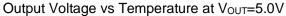
Notes:

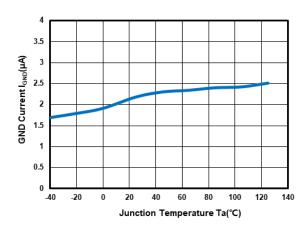
- 1. $V_{OUT(S)}$: Output voltage when $V_{IN}=V_{OUT}+2V$, $I_{OUT}=1$ mA.
- 2. $V_{DROP}=V_{IN1} (V_{OUT(S)} \times 0.98)$ where V_{IN1} is the input voltage when $V_{OUT} = V_{OUT(S)} \times 0.98$.
- 3. ILIM: Output current when $V_{IN}=V_{OUT(S)}+2V$ and $V_{OUT}=0.95*V_{OUT(S)}$.
- 4. VOUT pin should be shorted to GND pin, and the impedance between them is less than 0.1 ohm.

■ Typical Performance Characteristics

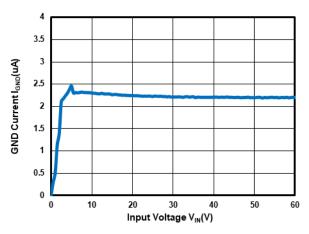
Test Conditions: V_{IN}=V_{OUT}+2.0V, C_{IN}=2.2µF, C_{OUT}=2.2µF, Ta=25℃, unless otherwise indicated.



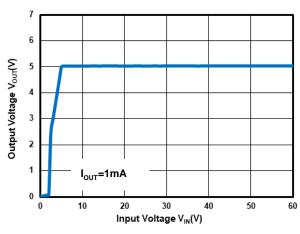




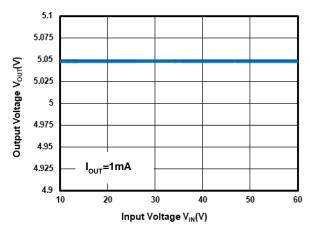
GND Current vs Temperature at V_{OUT}=5.0V



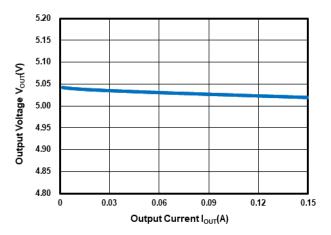
GND Current vs Input Voltage at Vout=5.0V



Output Voltage vs Input Voltage at Vout=5.0V



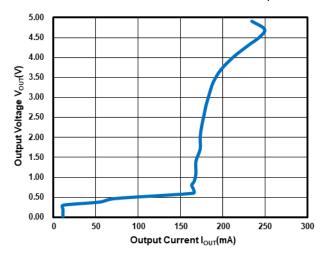
Output Voltage vs Input Voltage at V_{OUT}=5.0V

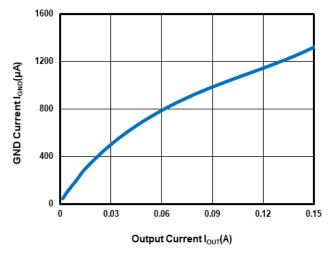


Output Voltage vs Output Current at Vout=5.0V

■ Typical Performance Characteristics (Continued)

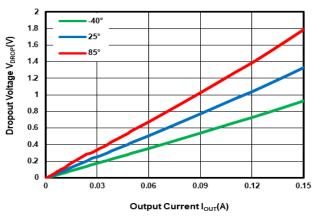
Test Conditions: $V_{IN}=V_{OUT}+2.0V$, $C_{IN}=2.2\mu F$, $C_{OUT}=2.2\mu F$, unless otherwise indicated.

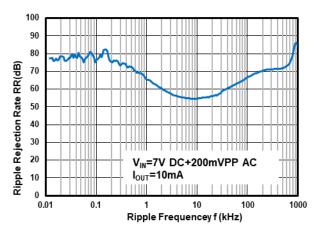




Output Current Fold-back at Vout=5.0V

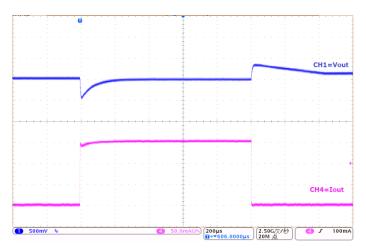
GND Current vs Output Current at V_{OUT}=5.0V

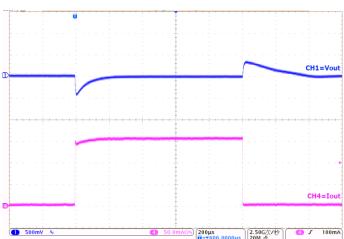




Dropout Voltage vs Temperature at VOUT=5.0V

Power Supply Rejection Ratio at V_{OUT}=5.0V

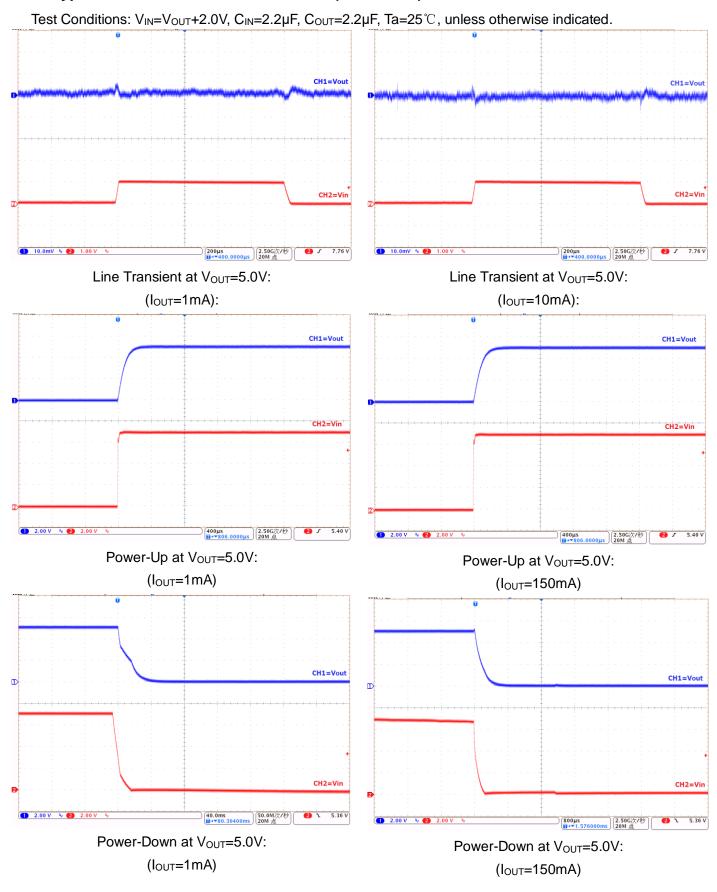




Load Transient at V_{OUT}=5.0V: (I_{OUT}=0mA~150mA~0mA)

Load Transient at V_{OUT}=5.0V: (I_{OUT}=1mA~150mA~1mA)

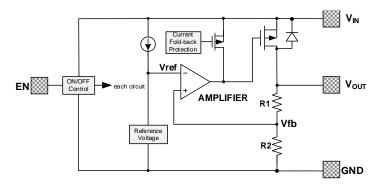
■ Typical Performance Characteristics (Continued)



■ Operational Explanation

1. Output voltage control

The voltage divided by resistors R1 and R2 is compared with the internal reference voltage by the error amplifier. The amplifier output then drives the P-channel MOSFET connected to the V_{OUT} pin. The output voltage at the V_{OUT} pin is regulated by this negative feedback system. The current limit circuit and short protect circuit operate in relation to output current level. Further, the IC's internal circuitry can be in operation or shutdown modes controlled by the CE pin's signal.



2. Pass transistor

The pass transistor with low turn-on resistance used in MD7680 is a P-channel MOSFET. If the potential on V_{OUT} pin is higher than VIN, it is possible that IC will be destroyed due to reverse current which is caused by parasitic diodes between V_{IN} and V_{OUT} . Therefore, the V_{OUT} pin potential exceeds V_{IN} +0.3V is not allowed.

3. Current foldback and over temperature protection

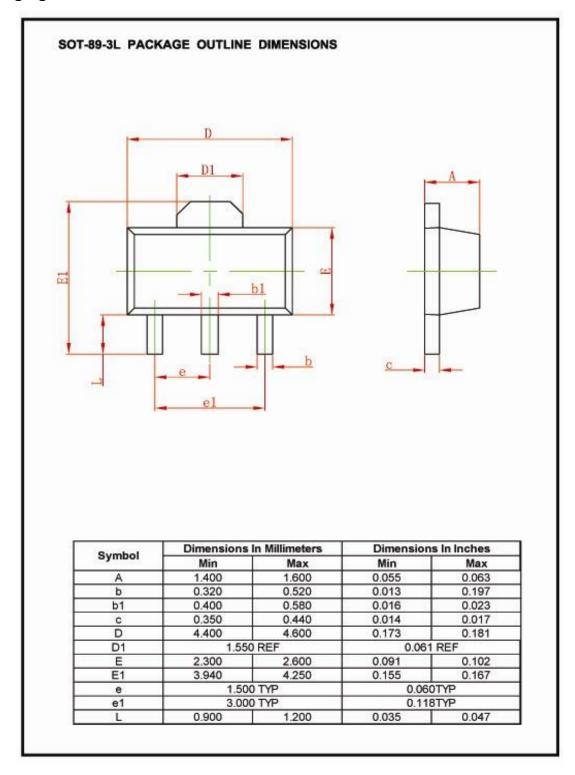
The MD7680 series includes a combination of a fixed current limiter circuit and a foldback circuit, which aid the operations of the current limiter and circuit protection. When the load current reaches the current limit level, the fixed current limiter circuit operates and output voltage drops. As a result of this drop in output voltage, the foldback circuit operates, output voltage drops further and output current decreases. This design can prevent the chip be damaged due to over temperature, moreover, the heat dissipation is limited by the package type.

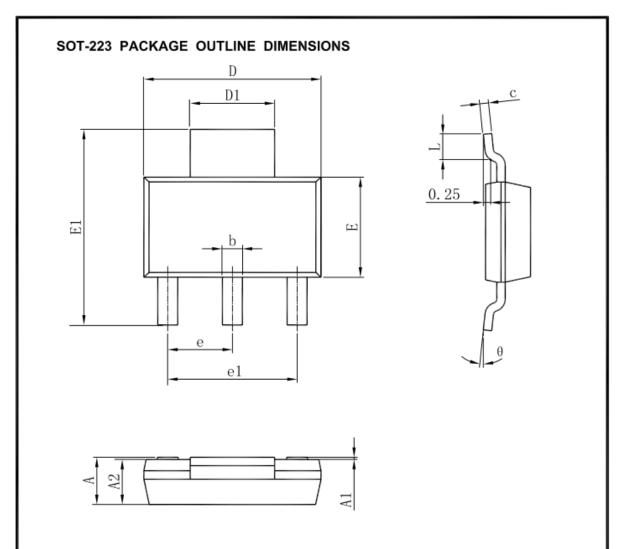
Special attention should be paid to that the product of the dropout voltage on the chip and the output current must be smaller than the heat dissipation. If power consumption on the chip is more than the heat dissipation, OTP will protect the chip from damaging due to over temperature.

■ Notes:

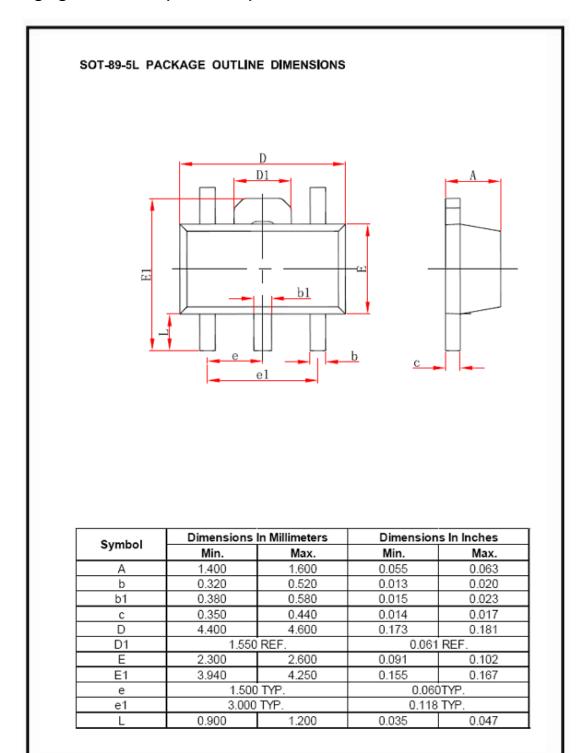
- 1. The input and output capacitors should be placed as close as possible to the IC.
- 2. If the impedance of the power supply is high, which is caused by forgetting installing input capacitor or installing too small value capacitor, the oscillation may occur.
- 3. Pay attention to the operation conditions of input and output voltage and load current, such that the power consumption in the IC should not exceed the allowable power consumption of the package even though the chip has short circuit protection.
- 4. IC has a built-in anti-static protection (ESD) circuit, but please do not add excessive stress to the IC.

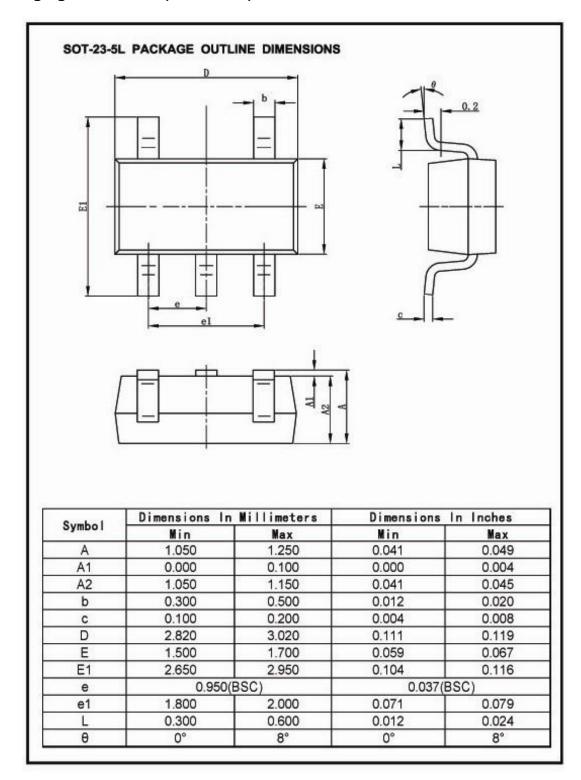
■ Packaging Information

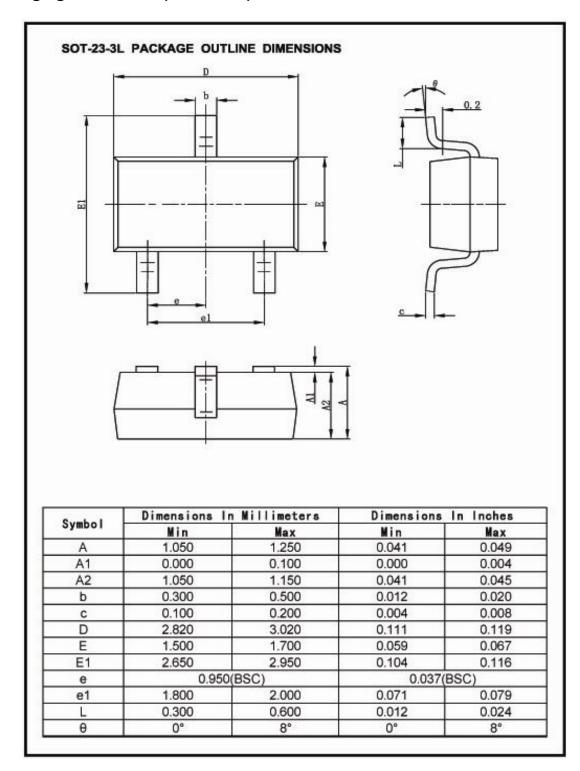


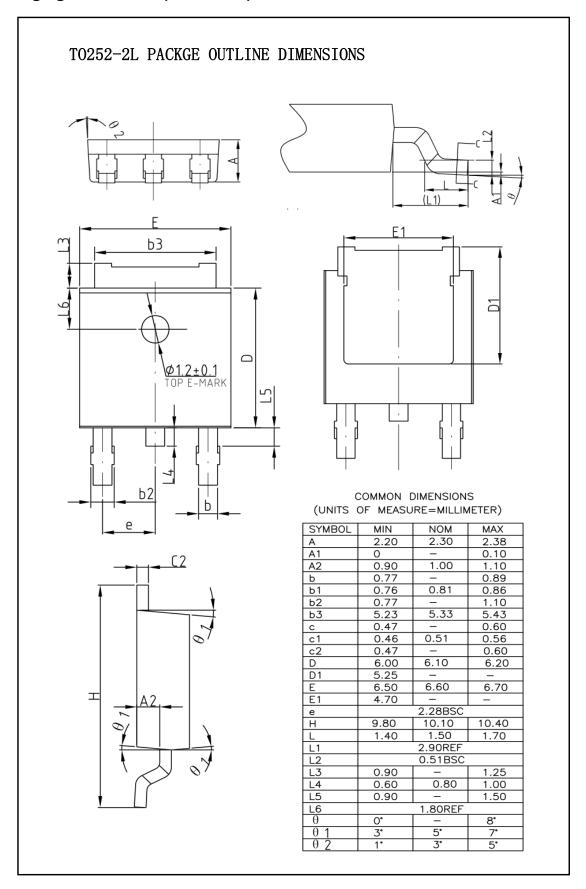


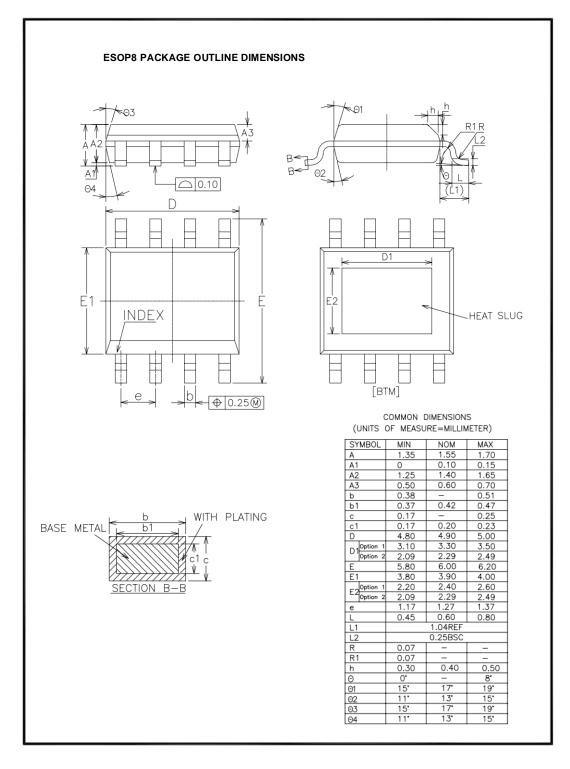
Symbol	Dimensions In	Millimeters	Dimensions	In Inches
	Min	Max	Min	Max
Α	1.520	1.800	0.060	0.071
A1	0.000	0.100	0.000	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.820	0.026	0.032
С	0.250	0.350	0.010	0.014
D	6.200	6.400	0.244	0.252
D1	2.900	3.100	0.114	0.122
E	3.300	3.700	0.130	0.146
E1	6.830	7.070	0.269	0.278
е	2.300(BSC)		0.091(BSC)	
e1	4.500	4.700	0.177	0.185
L	0.900	1.150	0.035	0.045
θ	0°	10°	0°	10°











For the newest datasheet, please see the website: Version V1.0 20231128

www.md-ic.com.cn